

# QM300HA-2H

HIGH POWER SWITCHING USE  
INSULATED TYPE

QM300HA-2H



- **IC** Collector current ..... **300A**
- **V<sub>CEX</sub>** Collector-emitter voltage ..... **1000V**
- **h<sub>FE</sub>** DC current gain ..... **75**
- **Insulated Type**
- **UL Recognized**

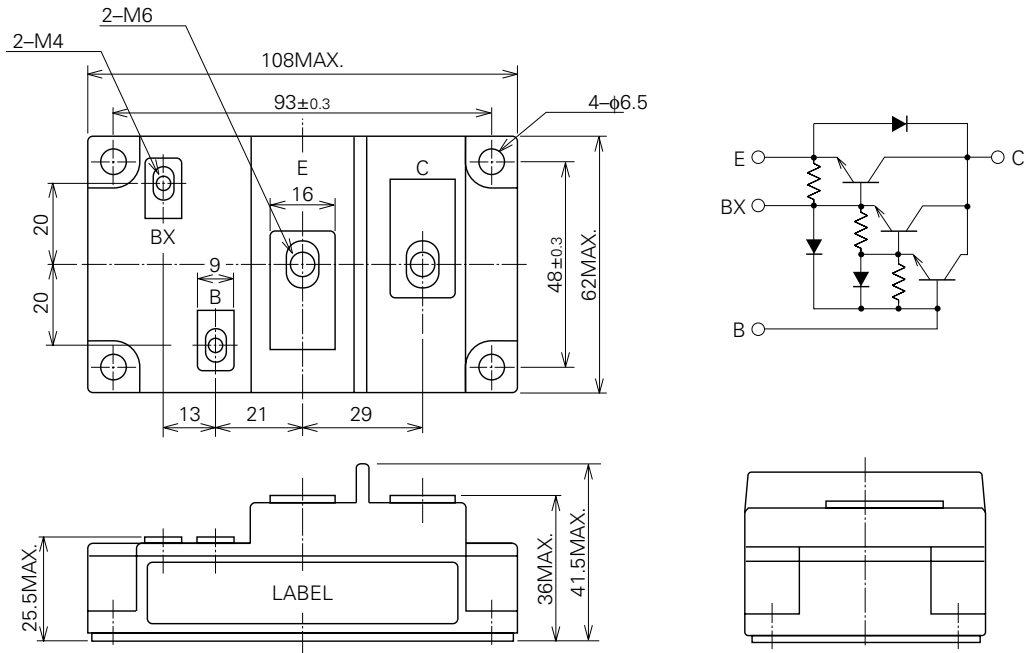
Yellow Card No. E80276 (N)  
File No. E80271

## APPLICATION

Inverters, Servo drives, DC motor controllers, NC equipment, Welders

## OUTLINE DRAWING & CIRCUIT DIAGRAM

Dimensions in mm



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## ABSOLUTE MAXIMUM RATINGS (T<sub>j</sub>=25°C, unless otherwise noted)

Symbol	Parameter	Conditions	Ratings	Unit
VCEX (SUS)	Collector-emitter voltage	I <sub>C</sub> =1A, V <sub>EB</sub> =2V	1000	V
VCEX	Collector-emitter voltage	V <sub>EB</sub> =2V	1000	V
VCBO	Collector-base voltage	Emitter open	1000	V
VEBO	Emitter-base voltage	Collector open	7	V
I <sub>C</sub>	Collector current	DC	300	A
-I <sub>C</sub>	Collector reverse current	DC (forward diode current)	300	A
P <sub>C</sub>	Collector dissipation	T <sub>C</sub> =25°C	1980	W
I <sub>B</sub>	Base current	DC	16	A
-I <sub>CSM</sub>	Surge collector reverse current (forward diode current)	Peak value of one cycle of 60Hz (half wave)	3000	A
T <sub>j</sub>	Junction temperature		-40~+150	°C
T <sub>stg</sub>	Storage temperature		-40~+125	°C
V <sub>iso</sub>	Isolation voltage	Charged part to case, AC for 1 minute	2500	V
—	Mounting torque	Main terminal screw M6	1.96~2.94	N·m
			20~30	kg·cm
		Mounting screw M6	1.96~2.94	N·m
			20~30	kg·m
		B terminal screw M4	0.98~1.47	N·m
BX terminal screw M4	0.98~1.47	N·m		
—	Weight	Typical value	460	g

## ELECTRICAL CHARACTERISTICS (T<sub>j</sub>=25°C, unless otherwise noted)

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
I <sub>C</sub> EX	Collector cutoff current	V <sub>CE</sub> =1000V, V <sub>EB</sub> =2V	—	—	4.0	mA
I <sub>C</sub> BO	Collector cutoff current	V <sub>CB</sub> =1000V, Emitter open	—	—	4.0	mA
I <sub>E</sub> BO	Emitter cutoff current	V <sub>EB</sub> =7V	—	—	400	mA
V <sub>CE</sub> (sat)	Collector-emitter saturation voltage	I <sub>C</sub> =300A, I <sub>B</sub> =6A	—	—	2.5	V
V <sub>BE</sub> (sat)	Base-emitter saturation voltage		—	—	3.5	V
-V <sub>CEO</sub>	Collector-emitter reverse voltage	-I <sub>C</sub> =300A (diode forward voltage)	—	—	1.85	V
h <sub>FE</sub>	DC current gain	I <sub>C</sub> =300A, V <sub>CE</sub> =2.8V/5V	75/100	—	—	—
t <sub>on</sub>	Switching time	V <sub>CC</sub> =600V, I <sub>C</sub> =300A, I <sub>B1</sub> =-I <sub>B2</sub> =6A	—	—	3.0	μs
t <sub>s</sub>			—	—	15	μs
t <sub>f</sub>			—	—	3.0	μs
R <sub>th</sub> (j-c) Q	Thermal resistance (junction to case)	Transistor part	—	—	0.063	°C/W
R <sub>th</sub> (j-c) R		Diode part	—	—	0.3	°C/W
R <sub>th</sub> (c-f)	Contact thermal resistance (case to fin)	Conductive grease applied	—	—	0.04	°C/W